

50V P-Channel Enhancement Mode MOSFET

• General Description

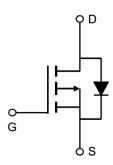
BSS84 combines advanced MOSFET technology with a low resistance package to provide extremely low $R_{DS(ON)}$. This device is most suitable to load-switch or PWM applications.

Applications

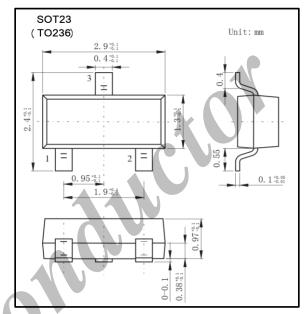
- DC/DC converter for portable devices
- Load switch

Product Summary

 $\begin{array}{ll} V_{DS} & .50V \\ I_{D} & -130mA \\ R_{DS(ON)} \left(at \ V_{GS} = -5V \right) & < 10\Omega \end{array}$









• Absolute Maximum Ratings Ta = 25°C

Parameter	Symbol	Rating	Unit		
Drain-Source Voltage	V_{DS}	-50	V		
Gate-Source Voltage	V_{GS}	±20	V		
Continuous Drain Current	I _D	-130	mA		
Pulsed Drain Current	I _{DM}	-520			
Power Dissipation	P_{D}	225	mW		
Thermal Resistance. Junction-to-Ambient t ≤ 10s	$R_{ hetaJA}$	556	°C/W		
Junction Temperature	τJ	150	°C		
Storage Temperature Range	Тѕтс	-55 to 150			

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• Electrical Characteristics Ta = 25°C

Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Drain-Source Breakdown Voltage	V_{DSS}	$I_D = -250 \mu A$, $V_{GS} = 0 V$	-50			V	
Zero Gate Voltage Drain Current	т	V_{DS} =-25V, V_{GS} =0V			-0.1		
	I_{DSS}	V_{DS} =-50V, V_{GS} =0V		4	-15	μA	
Gate-Body leakage current	I_{GSS}	V_{DS} =0V, V_{GS} =±20V			±10	μΑ	
Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS}=V_{GS}$, $I_{D}=-1mA$	-0.8	•	-2	V	
Static Drain-Source On-Resistance	R _{DS(ON)}	V_{GS} =-5V, I_D =-100mA			10	Ω	
Forward Transconductance	$\mathbf{g}_{ ext{FS}}$	V_{DS} =-25V, I_D =-100mA, f=1KHz	50	J		mS	
Input Capacitance	C_{iss}			30			
Output Capacitance	C_{oss}	V_{GS} =0V, V_{DS} =-5V, f=1MHz		10		pF	
Reverse Transfer Capacitance	C_{rss}			5			
Turn-On Delay Time	$t_{D(on)}$			2.5			
Turn-On Rise Time	t_{r}	V_{DD} =-15V, I_{D} =-0.25A,		1		ns	
Turn-Off Delay Time	$t_{\mathrm{D(off)}}$	$R_L=50\Omega$		16		115	
Turn-Off Fall Time	t_{f}			8			
Gate Charge	$Q_{\rm g}$			6		nC	
Maximum Body-Diode Continuous Current	I_S				-0.13	A	
Maximum Body-Diode Pulsed Current	I_{SM}				-0.52		
Diode Forward Voltage	V_{SD}	I_S =-130mA, V_{GS} =0V		-2.5		V	

• Ordering Information

Ordering Part Number	Package	MOQ
BSS84	SOT23 (TO236)	3,000 pcs / reel

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• Typical Characteristics

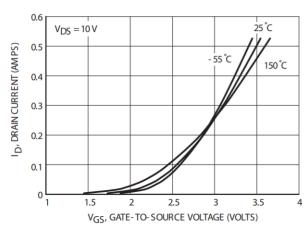


FIG1. Transfer Characteristics

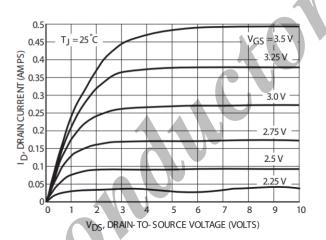


FIG2. On-Region Characteristics

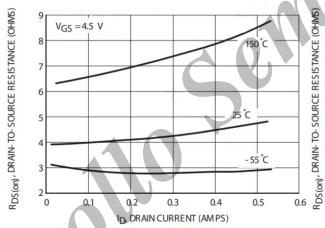


FIG3. On-Resistance versus Drain Current

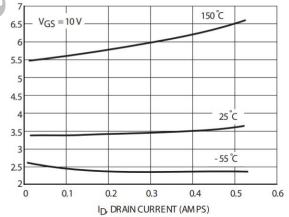
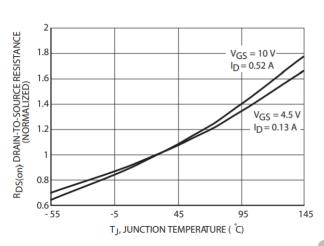


FIG4. On-Resistance versus Drain Current



• Typical Characteristics



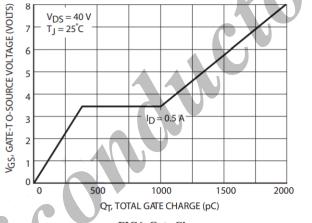


FIG5. On-Resistance Variation with Temperature



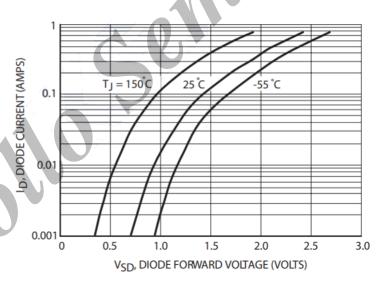


FIG7. Body Diode Forward Voltage

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